



Application Note: AN_SY8293

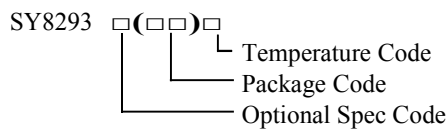
High Efficiency, 800kHz, 40V Input, 2.5A Non-synchronous Step Down Regulator

General Description

The SY8293 is a high efficiency 800 kHz, adaptive constant OFF time controlled non-synchronous step-down DC-DC regulator capable of delivering 2.5A output current respectively. The SY8293 can operate over a wide input voltage range from 5V to 40V and integrate the main switch with very low $R_{DS(ON)}$ to minimize the conduction loss.

Low output voltage ripple and small external inductor and capacitor sizes are achieved with 800 kHz switching frequency.

Ordering Information



Ordering Number	Package type	Note
SY8293FCC	SO8E	--

Features

- 5-40V input voltage range
- Low $R_{DS(ON)}$ for internal N-channel Power FET: 180 mΩ
- 800kHz switching frequency
- Adaptive constant OFF time control
- Internal softstart limits the inrush current
- 2% 0.6V reference
- RoHS Compliant and Halogen Free
- Compact package: SO8E

Applications

- Set Top Box
- Portable TV
- Access Point Router
- DSL Modem
- LCD TV

Typical Applications

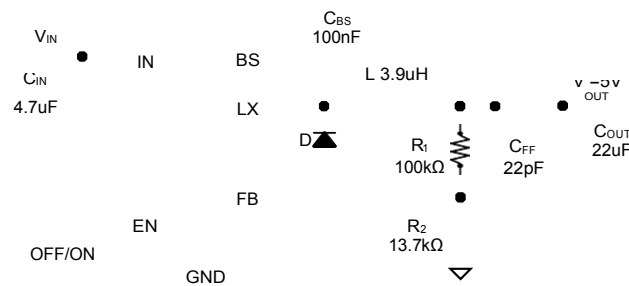
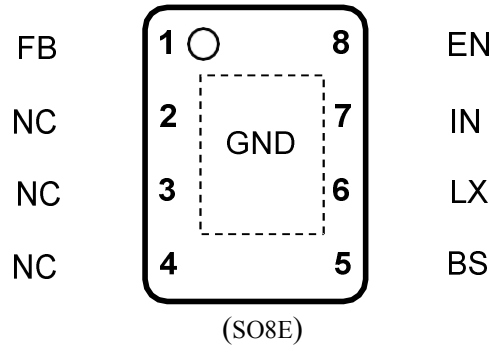


Figure 1. Schematic Diagram

Pinout (top view)



Top Mark: ARZxyz (Device code: ARZ, x=year code, y=week code, z=lot number code)

Pin Name	Pin Number	Pin Description
FB	1	Output Feedback Pin. Connect this pin to the center point of the output resistor divider (as shown in Figure 1) to program the output voltage: $V_{OUT}=0.6*(1+R1/R2)$
GND	Exposed paddle	Ground pin
BS	5	Boot-Strap Pin. Supply high side gate driver. Decouple this pin to LX pin with 0.1uF ceramic cap.
LX	6	Inductor pin. Connect this pin to the switching node of inductor
IN	7	Input pin. Decouple this pin to GND pin with at least 1uF ceramic cap
EN	8	Enable control. Pull high to turn on. Do not float.
NC	2, 3, 4	Not connected.

Absolute Maximum Ratings (Note 1)

Supply Input Voltage	-----V
Enable Voltage	----- $V_{IN} + 0.6V$
FB Voltage	----- 3.6V
BS to LX Voltage	----- 3.6V
Power Dissipation, PD @ TA = 25°C, SO8E	----- 3.3W
Package Thermal Resistance (Note 2)	
θ_{JA}	----- 30°C/W
θ_{JC}	----- 10°C/W
Junction Temperature Range	----- 150°C
Lead Temperature (Soldering, 10 sec.)	----- 260°C
Storage Temperature Range	----- 65°C to 150°C

Recommended Operating Conditions (Note 3)

Supply Input Voltage	----- V to 40V
BS to LX Voltage	----- 3.3V
Junction Temperature Range	----- 40°C to 125°C
Ambient Temperature Range	----- 40°C to 85°C



Electrical Characteristics

($V_{IN} = 12V$, $V_{OUT} = 5V$, $L=3.9\mu H$, $C_{OUT}=22\mu F$, $T_A = 25^\circ C$, $I_{OUT} = 1A$ unless otherwise specified)

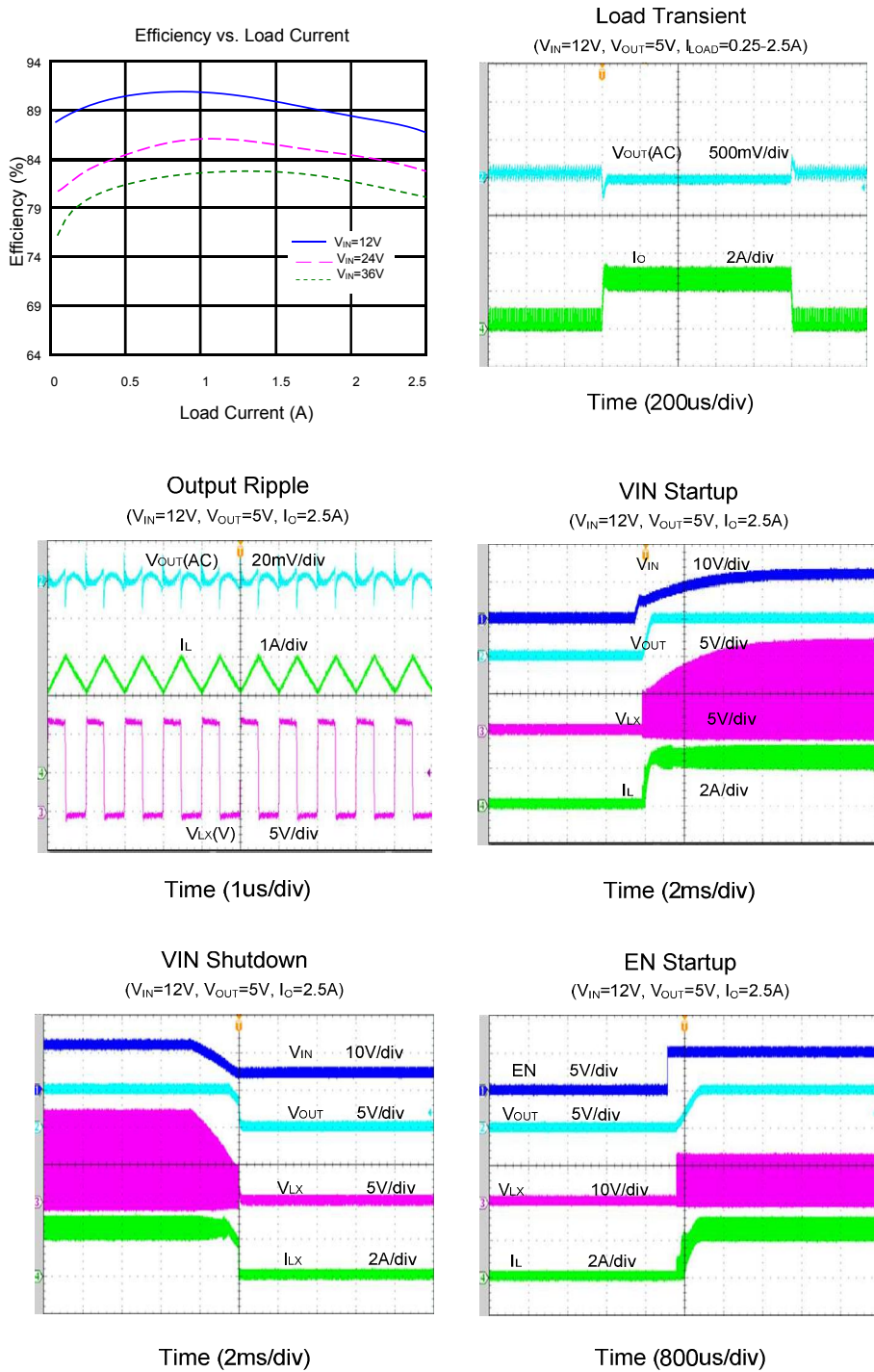
Parameter	Symbol	Test Conditions	Min	Typ	Max	Unit
Input Voltage Range	V_{IN}		5		40	V
Input UVLO Threshold	V_{UVLO}	Rising		4.5		V
Input UVLO Threshold		Falling		4.3		V
Input UVLO Hysteresis	V_{UVLO_HYS}			200		mV
Quiescent Current	I_Q	$I_{OUT}=0$, $V_{FB}=V_{REF}\times 105\%$		160		μA
Shutdown Current	I_{SHDN}	EN=0			10	μA
Feedback Reference Voltage	V_{REF}		0.588	0.6	0.612	V
FB Input Current	I_{FB}	$V_{FB}=V_{IN}$	-50		50	nA
Power FET RON	$R_{DS(ON)1}$			180		m Ω
Power FET Current Limit	I_{LIM}		3.4			A
EN Rising Threshold	V_{ENH}		1.5			V
EN Falling Threshold	V_{ENL}				0.4	V
Minimum OFF Time	T_{OFF}				100	ns
Minimum ON Time	T_{OFF}				100	ns
Maximum ON Time	T_{ON}			2		us
Oscillator Frequency	F_{OSC}			800		kHz
Thermal Shutdown Temperature	T_{SD}			150		$^\circ C$
Thermal Shutdown Recovery Hysteresis	T_{HYS}			15		$^\circ C$

Note 1: Stresses beyond the “Absolute Maximum Ratings” may cause permanent damage to the device. These are stress ratings only. Functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

Note 2: θ_{JA} is measured in the natural convection at $T_A = 25^\circ C$ on a low effective single layer thermal conductivity test board of JEDEC 51-3 thermal measurement standard.

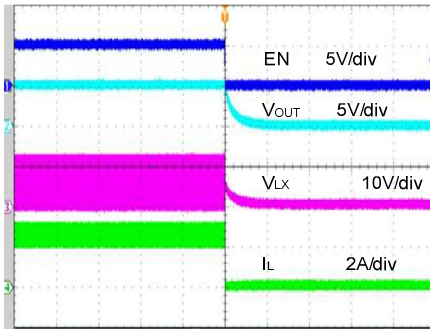
Note 3: The device is not guaranteed to function outside its operating conditions.

Typical Performance Characteristics



EN Shutdown

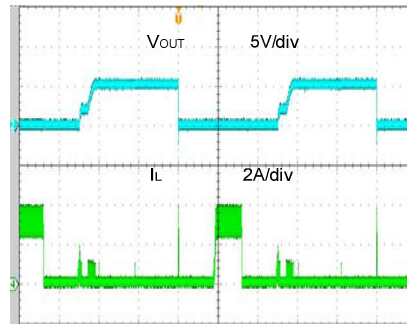
($V_{IN}=12V$, $V_{OUT}=5V$, $I_o=2.5A$)



Time (200us/div)

Short Circuit Protection

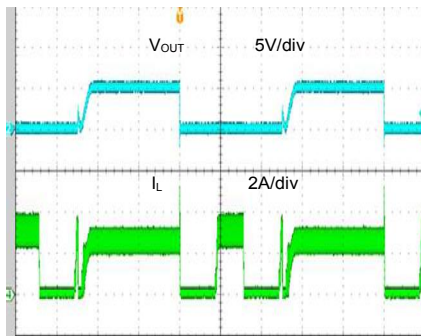
($V_{IN}=12V$, $V_{OUT}=5V$, 0A~short)



Time (2ms/div)

Short Circuit Protection

($V_{IN}=12V$, $V_{OUT}=5V$, 2.5A~short)



Time (2ms/div)

Operation


SY8293 is an asynchronous buck regulator IC that integrates the PWM control, main switch on the same die. With ultra low Rds(on) power switch and proprietary PWM control, this regulator IC can achieve high efficiency and fast transient response. High switch frequency minimizes the external inductor and capacitor size, thus minimize the PCB area and cost. SY8293 also features cycle by cycle current limit, output short circuit protection and thermal shutdown protection.

Applications Information

Because of the high integration in the SY8293 IC, the application circuit based on this regulator IC is rather simple. Only input capacitor C_{IN}, output capacitor C_{OUT}, output inductor L, rectifier diode D and feedback resistors (R₁ and R₂) need to be selected for the targeted applications.

Feedback resistor dividers R₁ and R₂:

Choose R₁ and R₂ to program the proper output voltage. To minimize the power consumption under light loads, it is desirable to choose large resistance values for both R₁ and R₂. A value of between 10kΩ and 1MΩ is highly recommended for both resistors. If V_{out} is 5V, R₁=100k is chosen, then using following equation, R₂ can be calculated to be 13.7k:

$$R_2 = \frac{0.6V}{V_{OUT} - 0.6V} R_1$$


Input capacitor C_{IN}:

The ripple current through input capacitor is calculated as:

$$I_{CIN_RMS} = I_{OUT} \cdot \sqrt{D(1-D)}$$

To minimize the potential noise problem, place a typical X5R or better grade ceramic capacitor really close to the IN pin and the negative end of rectifier. A low ESR ceramic capacitor is recommended with greater than 4.7uF capacitance.

Output capacitor C_{OUT}:

The output capacitor is selected to handle the output ripple noise requirements. Both steady state ripple and transient requirements must be taken into consideration when selecting this capacitor. For the best performance, it is recommended to use X5R or better grade ceramic capacitor with greater than 22uF capacitance.

Output inductor L:

There are several considerations in choosing this inductor.

- 1) Choose the inductance to provide the desired ripple current. It is suggested to choose the ripple current to be about 40% of the maximum output current. The inductance is calculated as:

$$L = \frac{V_{OUT}(1 - V_{OUT}/V_{IN,MAX})}{F_{SW} \times I_{OUT,MAX} \times 40\%}$$

Where F_{SW} is the switching frequency and I_{OUT,MAX} is the maximum load current.

The SY8293 regulator IC is quite tolerant of different ripple current amplitude. Consequently, the final choice of inductance can be slightly off the calculation value without significantly impacting the performance.

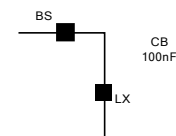
- 2) The saturation current rating of the inductor must be selected to be greater than the peak inductor current under full load conditions.

$$I_{SAT, MIN} > I_{OUT, MAX} + \frac{V_{OUT}(1 - V_{OUT}/V_{IN,MAX})}{2 \cdot F_{SW} \cdot L}$$

- 3) The DCR of the inductor and the core loss at the switching frequency must be low enough to achieve the desired efficiency requirement. It is desirable to choose an inductor with DCR < 50mΩ to achieve a good overall efficiency.

External Bootstrap Cap

This capacitor provides the gate driver voltage for internal high side MOSFET. A 100nF low ESR ceramic capacitor connected between BS pin and LX pin is recommended.



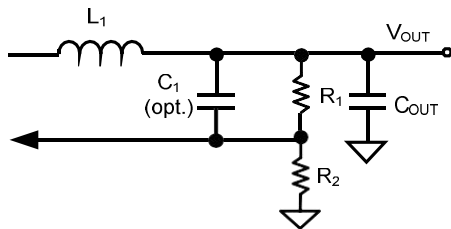
Rectifier Diode

Because of high switching speed of SY8293, a schottky diode with low forward voltage and fast switching

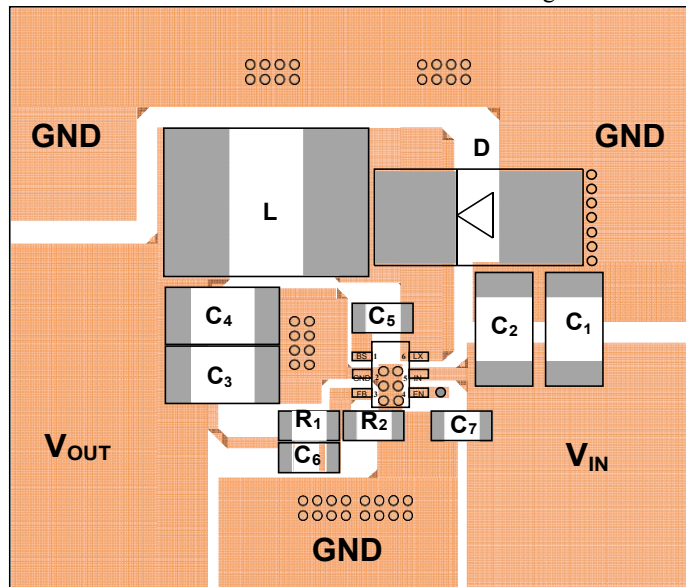
speed is desirable for the application. The voltage rating of the diode must be higher than maximum output voltage. The diode's average and peak current rating should exceed the average output current and peak current.

Load Transient Considerations:

The SY8293 regulator IC integrates the compensation components to achieve good stability and fast transient responses. In some applications, adding a small ceramic cap in parallel with R1 may further speed up the load transient response and is it is recommended for high step load applications.



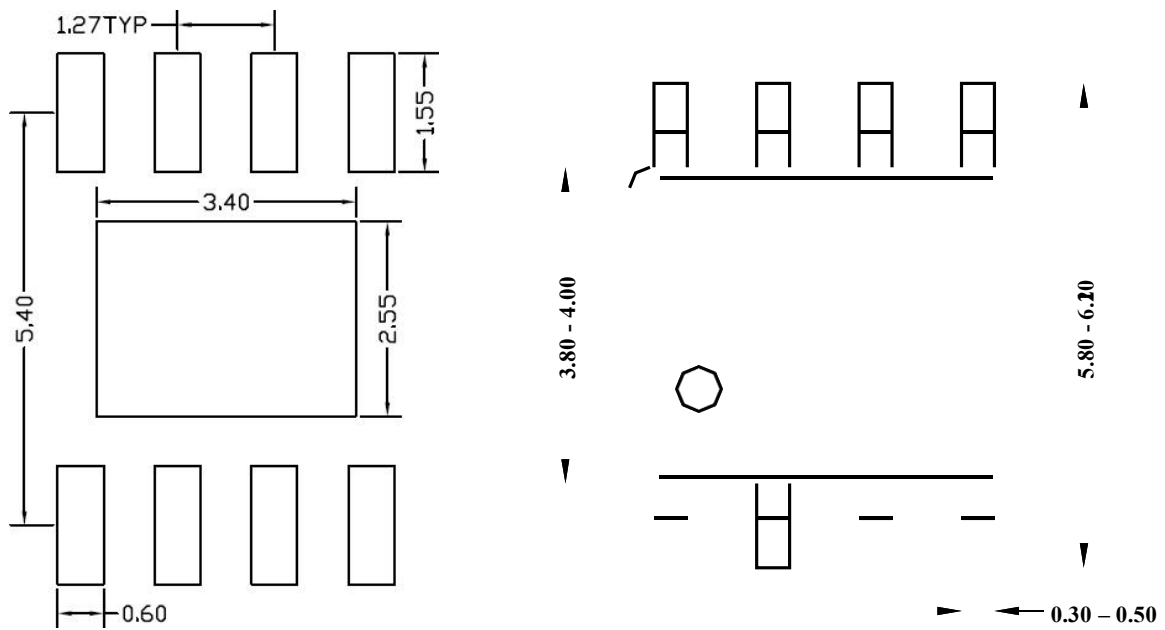
Layout Design:



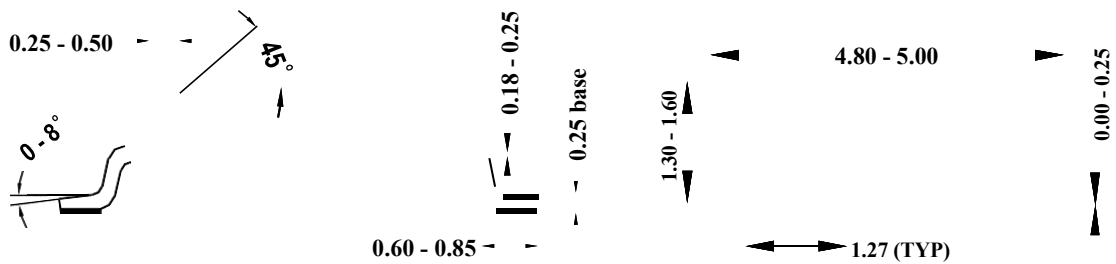
The layout design of SY8293 regulator is relatively simple. For the best efficiency and minimum noise problem, we should place the following components close to the IC: C_{IN}, L, R1 and R2.

- 1) It is desirable to maximize the PCB copper area connecting to GND pin to achieve the best thermal and noise performance. If the board space allowed, a ground plane is highly desirable.
- 2) The loop area formed by IN, LX, C_{IN} and the rectifier must be minimized.
- 3) The PCB copper area associated with LX pin must be minimized to avoid the potential noise problem.
- 4) The components R₁ and R₂, and the trace connecting to the FB pin must NOT be adjacent to the LX net on the PCB layout to avoid the noise problem.
- 5) If the system chip interfacing with the EN pin has a high impedance state at shutdown mode and the IN pin is connected directly to a power source, it is desirable to add a pull down 1Mohm resistor between the EN and GND pins to prevent the noise from falsely turning on the regulator at shutdown mode.

SO8-E Package Outline & PCB layout



Recommended Pad Layout



Notes: All dimension in MM
All dimension don't not include mold flash & metal burr